# Power transistor (60V, 3A)

# 2SC5825

# Features

- 1) High speed switching.
- (Tf:Typ.:30ns at Ic = 3A)
- 2) Low saturation voltage, typically (Typ.: 200mV at Ic = 2A, IB = 0.2mA)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2073

# Applications

Low frequency amplifier High speed switching

#### ●Structure

NPN Silicon epitaxial planar transistor

# Packaging specifications

	Package	Taping	
Туре	Code	TL	
	Basic ordering unit (pieces)	2500	
2SC5825		0	

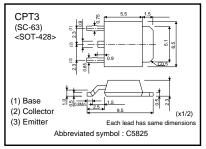
# Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	60	V	
Collector-emitter voltage		Vceo	60	V	
Emitter-base voltage		Vebo	6	V	
Collector current	Continuous	lc	3	А	
	Pulsed	СР	6	A *1	
Power dissipation		Pc	1.0	W *2	
		PC	10.0	W *3	
Junction temperature		Tj	150	°C	
Range of storage temperature		Tstg	-55 to 150	°C	

\*1 Pw=10ms

\*2 Each terminal mounted on a recommended land \*3 Tc=25°C

# •External dimensions (Unit : mm)



# Transistors

#### Electrical characteristics (Ta=25°C)

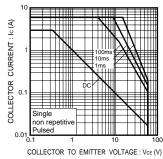
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Collector-emitter breakdown voltage	BVCEO	60	-	-	V	lc=1mA	
Collector-base breakdown voltage	ВУсво	60	-	-	V	Ic=100μA	
Emitter-base breakdown voltage	ВVево	6	-	-	V	lε=100μA	
Collector cut-off current	Ісво	-	-	1.0	μΑ	Vcb=40V	
Emitter cut-off current	lево	-	-	1.0	μΑ	Veb=4V	
Collector-emitter saturation voltage	Vce (sat)	-	200	500	mV	Ic=2A *1	
						Iв=200mA	
DC current gain	hfe	120	-	390	-	Vce=2V	
						Ic=100mA	
	fт	_	200	-	MHz	Vce=10V *1	
Transition frequency						IE= -100mA	
						f=10MHz	
	Соь	-	20	_	pF	Vcb=10V	
Corrector output capacitance						IE=0mA	
						f=1MHz	
Turn-on time	Ton	-	50	-	ns	Ic=3A *2	
Storage time	Tstg	-	150	-	ns	IB1=300mA IB2= −300mA Vcc≑25V	
Fall time	Tf	-	30	-	ns		

\*1 Non repetitive pulse \*2 See Switching charactaristics measurement cicuits

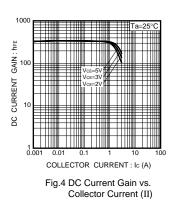
### •hfe RANK

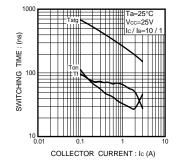
Q	R		
120–270	180–390		

#### •Electrical characteristic curves

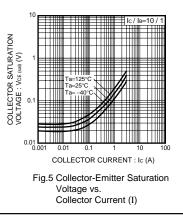












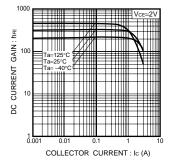
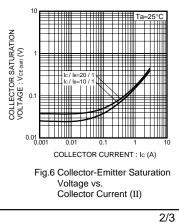


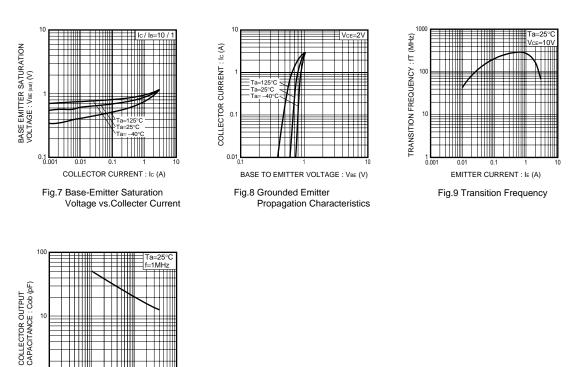
Fig.3 DC Current Gain vs. Collector Current (I)



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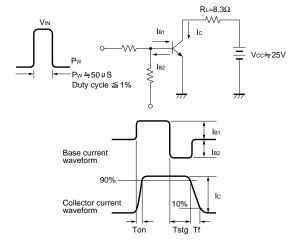
# Transistors



BASE TO COLLECTOR VOLTAGE : VCB (V)

Fig.10 Collector Output Capacitance

# •Switching characteristics measurement circuits



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